

CR25RM-12D

Thyristor

Medium Power Use

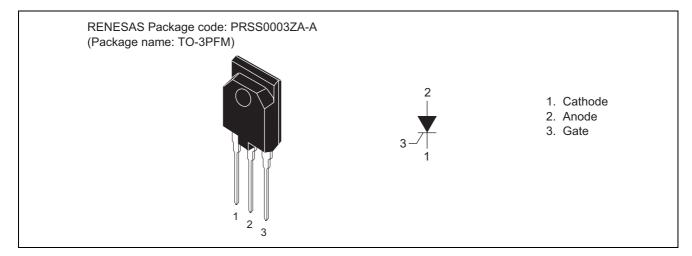
REJ03G1716-0100 Rev.1.00 Jul 08, 2008

Features

I_{T (AV)}: 25 A
 V_{DRM}: 600 V
 I_{GT}: 30 mA
 Viso: 2000 V

- Insulated Type
- Planar Passivation Type
- The product guaranteed maximum junction temperature of 150°C

Outline



Applications

Switching mode power supply, motor control, heater control, and other general purpose control applications

Maximum Ratings

Parameter	Symbol Voltage class		Unit	
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Repetitive peak reverse voltage	V_{RRM}	600	V	
Non-repetitive peak reverse voltage	V_{RSM}	720	V	
DC reverse voltage	V _{R (DC)}	480	V	
Repetitive peak off-state voltage	V_{DRM}	600	V	
DC off-state voltage	V _{D (DC)}	480	V	

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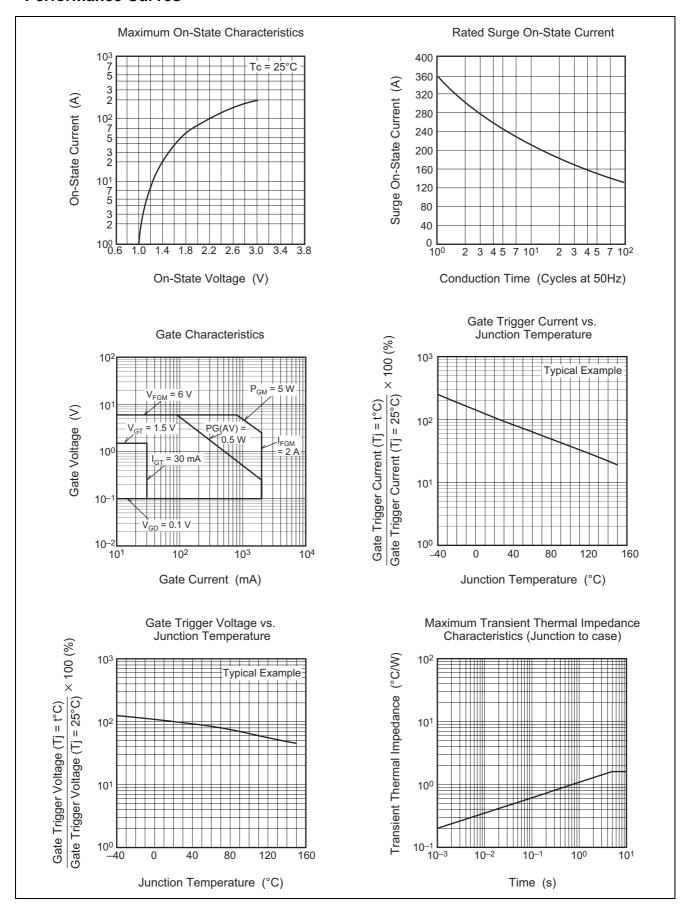
Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T (RMS)}	39.3	Α	
Average on-state current	I _{T (AV)}	25	А	Commercial frequency, sine half wave 180° conduction, Tc = 61°C
Surge on-state current	I _{TSM}	360	А	50 Hz sine half wave 1 full cycle, peak value, non-repetitive
I ² t for fusing	l ² t	648	A ² s	Value corresponding to 1 cycle of half wave 50 Hz, surge on-state current
Peak gate power dissipation	P _{GM}	5	W	
Average gate power dissipation	P _{G (AV)}	0.5	W	
Peak gate forward voltage	V_{FGM}	6	V	
Peak gate reverse voltage	V_{RGM}	10	V	
Peak gate forward current	I _{FGM}	2	Α	
Junction temperature	Tj	- 40 to +150	°C	
Storage temperature	Tstg	- 40 to +150	°C	
Mass	_	5.2	g	Typical value
Isolation voltage	Viso	2000	V	Ta = 25°C, AC 1 minute, each terminal to case

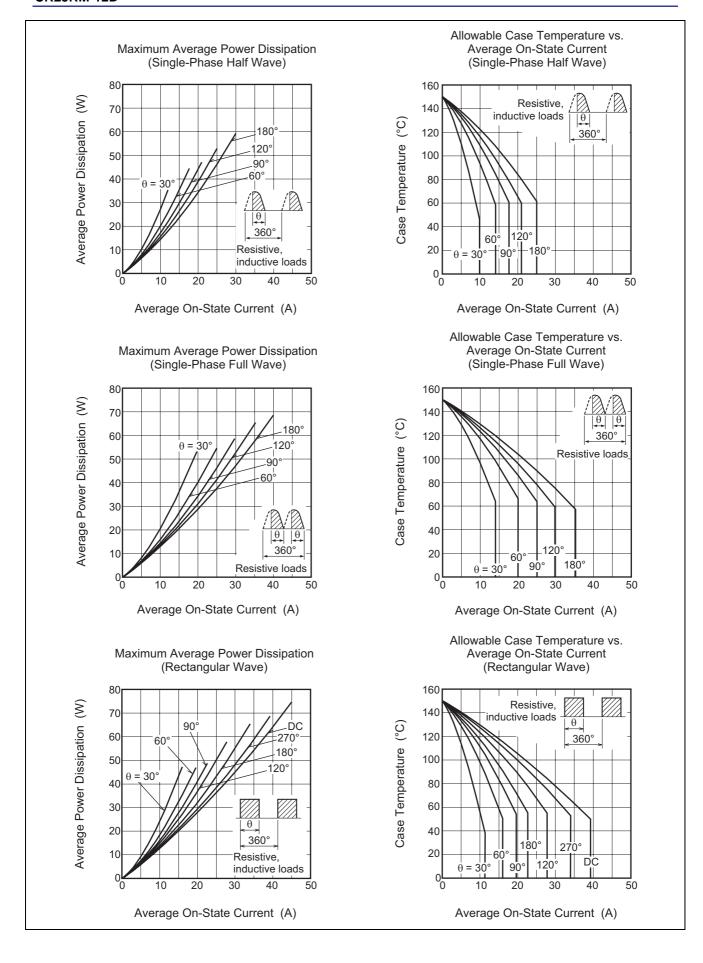
Electrical Characteristics

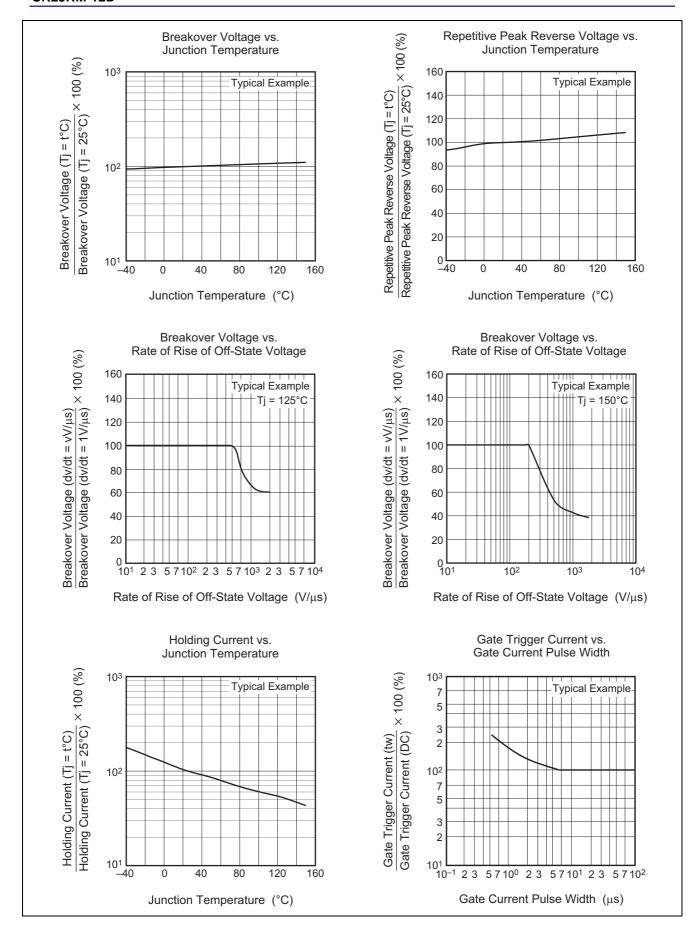
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak reverse current	I _{RRM}	_	_	2.0/5.0	mA	Tj = 125°C/150°C, V _{RRM} applied
Repetitive peak off-state current	I _{DRM}	_	_	2.0/5.0	mA	Tj = 125°C/150°C, V _{DRM} applied
On-state voltage	V_{TM}	_	_	1.6	V	Tc = 25°C, I _{TM} = 40 A, instantaneous value
Gate trigger voltage	V_{GT}	_	_	1.5	V	Tj = 25°C, V _D = 6 V, I _T = 1 A
Gate non-trigger voltage	V_{GD}	0.2/0.1	_	_	V	$Tj = 125$ °C/150°C, $V_D = 1/2 V_{DRM}$
Gate trigger current	I _{GT}	_	_	30	mA	$Tj = 25$ °C, $V_D = 6$ V, $I_T = 1$ A
Holding current	I _H	_	15	_	mA	Tj = 25°C, V _D = 12 V
Thermal resistance	R _{th (j-c)}	_	_	1.6	°C/W	Junction to case ^{Note1}

Notes: 1. The contact thermal resistance $R_{th (c-f)}$ in case of greasing is 0.5°C/W .

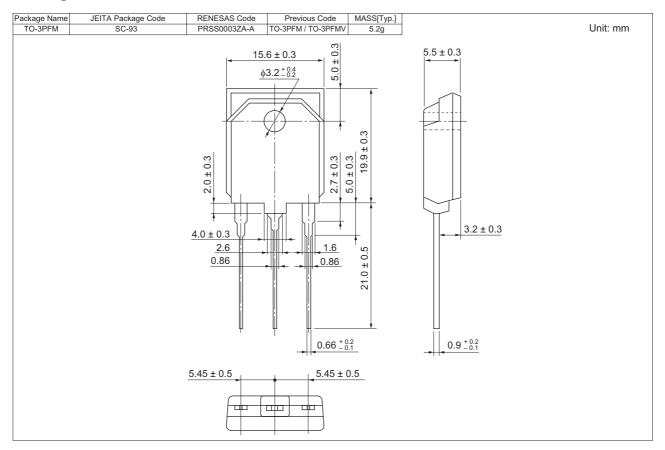
Performance Curves







Package Dimensions



Order Code

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Straight type	Magazine (Tube)	30	Type name	CR25RM-12D

Note: Please confirm the specification about the shipping in detail.

Renesas Technology Corp. sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

- Renesas lechnology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Notes:

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Renesas Technology America, Inc.

450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd.
Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7858/7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2377-3473

Renesas Technology Taiwan Co., Ltd. 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 3518-3399

Renesas Technology Singapore Pte. Ltd.
1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510